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VDD

GND

### Cosemitech

**Industry Product Group** 

### CH461A/CH461AN

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**REV 1.2** 

#### FEATURES and FUNCTIONAL DIAGRAM PACKAGE Enhanced sensitivity: will operate from only 45 Gauss typical, at 25°C allowing the use of smaller, potentially lower-cost magnets or wider air gaps Subminiature, SOT-23-3L surface mount package (CH461AS/CH461ANS) supplied on tape and reel allows for a compact design with automated component placement. helping to reduce manufacturing costs SOT-23 -3L Small, leaded, flat, TO-92S package (CH461AT/ CH461ANT) allows for a compact PCB layout Bipolar latching magnetics respond to alternating North and South poles, making these products well-suited for accurate speed sensing and RPM (revolutions per minute) measurement Wide operating voltage range of 3.8V to 30V makes these sensors useable in a wide range of applications TO-92S Built-in inductance freewheeling diode, with the OUT terminal high voltage discharge capability enhances the protection of APPLICATIONS the sensor and the circuits with which it is used Transportation Robust design: will operate up to 150 °C Speed and RPM RoHS-compliant material meets directive 2011/65/EU (revolutions per minute) sensina Tachometer, counter pickup Function Block Diagram Motor and fan control Electric window lift Convertible roof position Automotive transmission VREG OUT position ESD 1 Industrial Clamp ſΠ Hall Current ESD - Speed and RPM sensing Amplifie Comparato Sinking Clamp Output ſΠ Tachometer, counter pickup Π Flow-rate sensing 巾 Π П Programming Circuit Brushless dc (direct current) motor commutation Motor and fan control 巾 Robotics control Medical Motor assemblies Medication dispense control

#### DESCRIPTION

The CH461A and CH461AN are small, versatile digital Hall effect devices that are operated by the magnetic field from a permanent magnet or an electromagnet, designed to respond to alternating North and South poles.

These bipolar latching sensor ICs have enhanced sensitivity, which often allows for the use of less expensive magnets.

These sensor ICs are available in two package styles, the CH461AS/CH461ANS in the subminiature SOT-23-3L surface mount package and the CH461AT/ CH461ANT in the leaded, flat TO-92S package.

The CH461AS/CH461ANS's small size requires less PC board space, allowing it to be used in smaller assemblies. Its 3.5V capability allows for use in low voltage applications, promoting energy efficiency.

The CH461AS/CH461ANS is available on tape and reel; the CH461AT/ CH461ANT is available in a bulk package (1000 units per bag).



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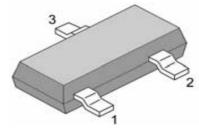
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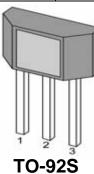
#### **1. Product Family Members**

Part Number	Marking ID	Description
CH461ASR	461A	Bipolar latching, Hall-effect digital sensor IC, SOT-23-3L package, tape and reel packing (3000 units per reel)
CH461ATB	461A	Bipolar latching, Hall-effect digital sensor IC, flat, TO-92S package, bulk packing (1000 units per bag)
CH461ANSR	461AN	Bipolar latching, Hall-effect digital sensor IC, SOT-23-3L package, tape and reel packing (3000 units per reel)
CH461ANTB	461AN	Bipolar latching, Hall-effect digital sensor IC, flat, TO-92S package, bulk packing (1000 units per bag)

#### 2. Pin Definitions and Descriptions

SOT-23-3L(S)	TO-92S(T)	Name	Туре	Function
1	1	VDD	Supply	Supply Voltage pin
2	3	OUT	Output	Open Collector Output pin (include freewheeling diode)
3	2	GND	Ground	Ground pin





SOT-23-3L

#### 3. Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Units
Supply Voltage	V <sub>DD</sub>	-	40	V
Reverse Voltage	V <sub>RDD</sub>	-	-0.3	V
Supply Current	I <sub>DD</sub>	-	20	mA
Output Voltage	V <sub>OUT</sub>	-0.3	40	V
Output Current	Ι <sub>Ουτ</sub>	-	20	mA
Operating Ambient Temperature	T <sub>A</sub>	-40	150	°C
Storage Temperature	Ts	-50	150	°C
Junction temperature	TJ	-50	165	°C
Magnetic Flux	В	No Limit Gau		Gauss

Note 1: Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum- rated conditions for extended periods may affect device reliability.

Note 2: Based on the Voltage Surge Test result (Automotive electronics test standard: AEC-Q200-007 REV A), the device which under the test is able to withstand dynamic voltage reach about 70V (worst case), and the current ability is able to be 0.28A (worst case). Though the test result is not a guarantee value, but the test result is a strong robust indication for device dynamic breakdown voltage and current.



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#### 4. ESD Protections

+/-4000	V
+/-400	V
+/-1500	V
	+/-400

1) HBM (human body mode, 100pF, 1.5 kohm ) according to MIL-STD-883H Method 3015.8

2) MM (Machine Mode C=200pF, R=0Ω) according to JEDEC EIA/JESD22-A115

3) CDM (charged device mode) according to JEDEC EIA/JESD22-C101F

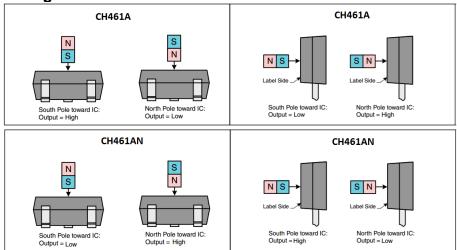
#### 5. Function Description

The CH461A/CH461AN exhibits latch magnetic switching characteristics. Therefore, it requires both south and north poles to operate properly.

The device behaves as a latch with symmetric operating and release switching points (BOP=|BRP|). This means magnetic fields with equivalent strength and opposite direction drive the output high and low.

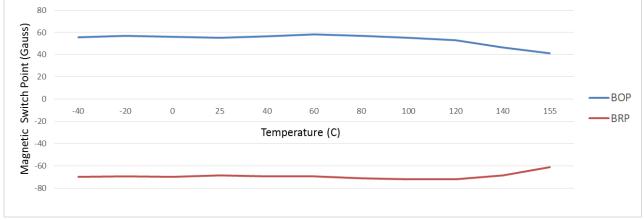
Removing the magnetic field  $(B\rightarrow 0)$  keeps the output in its previous state. This latching property defines the device as a magnetic memory.

A magnetic hysteresis BHYST keeps BOP and BRP separated by a minimal value. This hysteresis prevents output oscillation near the switching point.



#### 6. Magnetic Activation

#### 7. Temperature Characteristics





CH461A/CH461AN

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# 8. Parameters Specification (At 3.5V to 30V supply, 20mA load, TA= -40 °C to 150 °C except where otherwise specified.)

Symbol	Parameter	Test Condition	Min	Тур.	Max	Units
V <sub>DD</sub>	Supply voltage	-40 °C to 150 °C	3.5	-	30	V
I <sub>DD</sub>	Supply Current	$V_{DD} = 5V$	-	5.0	10	mA
V <sub>DSon</sub>	Output saturation voltage	at 20mA, Gauss >120	-	-	0.4	V
I <sub>OFF</sub>	Output Leakage Current	B<-120GS	-	-	10	uA
T <sub>R</sub>	Output rise time	V <sub>DD</sub> =12V at 25 °C C <sub>L</sub> = 20 pF	-	-	1.5	uS
Τ <sub>F</sub>	Output fall time	V <sub>DD</sub> =12V at 25 °C C <sub>L</sub> = 20 pF	-	-	1.5	uS
R <sub>TH</sub>	Thermal resistance: CH461AS (SOT-23-3L) CH461AT (TO-92S)	-	-	303 203	-	°C /W °C/W
B <sub>OP</sub>	CH461A Magnetic operating point	-40°C to 150°C	5	45	95	Gauss
DOP	CH461AN Magnetic operating point	-40°C to 150°C	-95	-45	-5	Gauss
B <sub>RP</sub>	CH461A Magnetic release point	-40°C to 150°C	-95	-45	-5	Gauss
DRP	CH461AN Magnetic release point	-40°C to 150°C	5	45	95	Gauss
B <sub>HYST</sub>	CH461A Magnetic hysteresis window	T <sub>A</sub> =25°C  B <sub>OP</sub> -B <sub>RP</sub>	60	90	120	Gauss
DHYST	CH461AN Magnetic hysteresis window	T <sub>A</sub> =25°C  B <sub>OP</sub> -B <sub>RP</sub>	60	90	120	Gauss
$F_{SW}$	Maximum Switching Frequency				100	KHz
Т	Operating temperature		-40	-	150	°C
Ts	Storage temperature:	-	-40	-	150	°C

#### NOTICE

Bipolar Hall-effect sensor ICs may have an initial output in either the ON or OFF state if powered up with an applied magnetic field in the differential zone (applied magnetic field >Brp and <Bop). Cosemitech recommends allowing 10  $\mu$ s for output voltage to stabilize after supply voltage has reached 5V.

#### NOTICE

The magnetic field strength (Gauss) required to cause the switch to change state (operate and release) will be as specified in the magnetic characteristics. To test the switch against the specified magnetic characteristics, the switch must be placed in a uniform magnetic field.



#### CH461A/CH461AN

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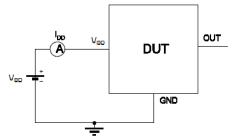
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#### 9. Test Conditions

Note: DUT=Device Under Test

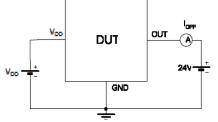
#### Supply Current



Note 1 - The supply current IDD represents the static supply current. OUT is left open during measurement

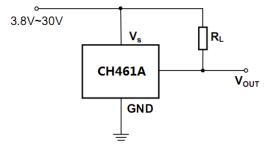
Note 2 - The device is put under magnetic field with B<BRP

#### Output Leakage Current

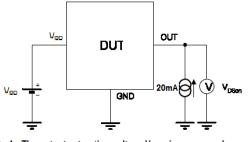


Note 1 - The device is put under magnetci field with B<BRP

#### **10. Typical Application Circuit**



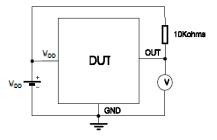
#### **Output Saturation Voltage**



Note 1 - The output saturation voltage VDSon is measeured at VDD=3.8V and VDD=24V

Note 2 - The device is put under magnetic field with B>Bop

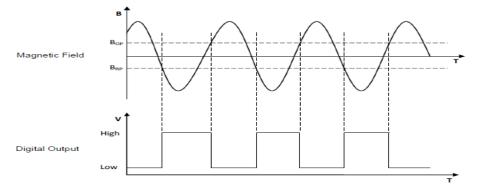
#### **Magenetic Thresholds**



Note 1 - Bop is determined by putting the device under magnetic field swept from BRPmin up to BoPmax until the output is switched on.

Note 2 - Bris determined by butting the device under magnetic field swept from BOPmax down to BRPmin until the output is switched off.

### 11. Typical Output Waveform (The TO-92S package as an example )





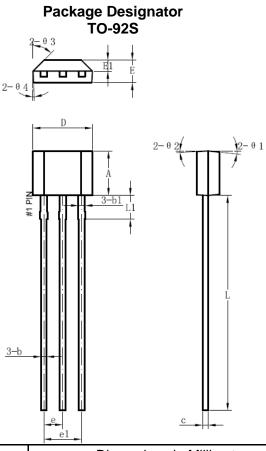
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### 12. Package Information:



Symbol	Dim	ensions in Millir	neters
Symbol	Min.	Тур.	Max.
A	2.9	3	3.1
b	0.35	0.39	0.56
b1		0.44	
С	0.36	0.38	0.51
D	3.9	4	4.1
E	1.42	1.52	1.62
E1		0.75	
е		1.27	
e1		2.54	
L	13.5	14.5	15.5
L1		1.6	
θ1		6°	
θ2		3°	
θ3		45°	

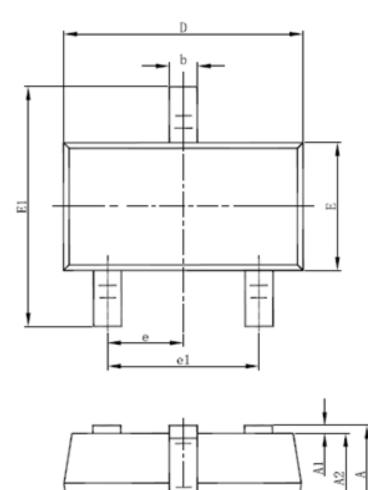


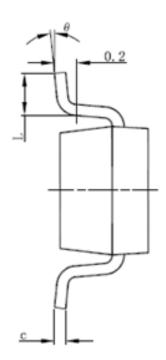
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### PACKAGE DESIGNATOR SOT-23-3L (CH462S)







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Sumbal	Dimensions In Millin		Dimensions	In Inches	
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	(BSC)	0.037(	BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

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